Photoluminescence experiment on quantum dots embedded in a large Purcell-factor microcavity

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It is usually assumed that when performing a photoluminescence experiment on a microcavity containing an inhomogeneously broadened quantum dot ensemble, the cavity mode appears as a positive peak with a linewidth that reflects the mode quality factor $Q$. We show in this paper that this conclusion is in general not true and that the measured mode linewidth depends strongly on the excitation power for microcavities having large Purcell factors. We analyze theoretically this effect in the case of the micropillar cavity, and we show that the same microcavity can give rise to a large variety of photoluminescence spectral signatures depending on the excitation power and collection setup. We finally give guidelines to measure the real cavity quality factor by photoluminescence.

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I. INTRODUCTION

For more than ten years, self-assembled quantum dots (QDs) have been recognized as an emitter of choice to study microcavity effects in semiconductor systems. One reason first shown in micropillar cavities is that their broad inhomogeneous emission linewidth allows one to probe microcavity modes in a simple photoluminescence (PL) experiment over a wide spectral range (typically 100 meV for InAs/GaAs QDs). Unlike quantum wells, the absorption induced by the QD array is in general negligible compared to the optical losses of the empty cavity. The measurement of the mode energies and quality factors using an ensemble of QDs as an internal broadband light source was successfully performed for micropillars, microdisks, and various photonic crystal structures. The demonstration of a large Purcell effect for QDs in micropillars opened later the way to numerous solid-state cavity quantum electrodynamics experiments (for a review see Ref. 8), including the vacuum Rabi flopping of a single QD (Refs. 9–11) with promising prospects for low-threshold lasers, single-photon sources, and possibly quantum information processing. In this paper, we come back to a basic question that (oddly enough) was not raised yet in the literature; what is exactly measured when a PL experiment is performed on a microcavity containing quantum dots? Since the first publication on the topic, it has been assumed that the cavity modes appear as positive peaks in the spectrum and that the linewidth of the PL peaks faithfully reflects their quality factor $Q$. Obviously, the QD-cavity system should at least satisfy two conditions for that. First of all, the number of QDs should be large enough to ensure a good “smoothness” of the spectrum of the internal light source. This condition simply writes $\Delta E_{\text{hom}} N > \Delta E_{\text{inh}}$, where $N$ is the total number of QDs within the mode area, $\Delta E_{\text{hom}}$ is the homogeneous linewidth of the QD transitions, and $\Delta E_{\text{inh}}$ is the inhomogeneous linewidth of the QD distribution. Second, the additional absorption losses introduced by the QD array should be much smaller than the empty cavity losses. We note that these two conditions are opposite: the first one favors high QD densities while the second one favors low QD densities. There are however large ranges of experimental parameters where both conditions can be fulfilled while having a large Purcell effect; such an example is given in Sec. II when the first microcavity example is introduced. We show in this paper that even when both conditions are fulfilled, the PL peaks do not reflect properly the $Q$’s of the cavity modes in general when the QDs experience a strong Purcell effect. More precisely, we show that the PL peak can be broadened by a factor as large as $(F_p+1)^{1/2}$ compared to the cavity mode for a weak excitation of the QD array ($F_p$ is the Purcell factor of the cavity). We also show that in the Purcell-enhancement regime, cavity modes can appear as dips as well as peaks in the PL spectra, depending on the experimental configuration that is used for photon collection. These effects are analyzed in more detail on the basis of a simple model accounting for the spatial dot distribution inside the cavity (the micropillar is taken as an example, although the results apply to all cavities) and the level structure of the QDs (excitonic and biexcitonic transitions). This analysis allows one to select several experimental protocols for a reliable measurement of the cavity $Q$ in a PL experiment using QDs as internal light source.

This paper is organized as follows. In Sec. II, we present the theoretical basis of this paper, and we demonstrate that the mode PL peak linewidth depends strongly on excitation power and reflects the actual cavity $Q$ only in the high excitation power limit. In Sec. III, we analyze the various spectra that can be obtained in PL on a microcavity containing QDs as a function of the collection setup. We discuss in Sec. IV the limits of our model and the various strategies that can be implemented to measure correctly in PL the quality factor of a large Purcell-factor microcavity.

II. PL LINEWIDTH OF CAVITY MODES IN THE PURCELL-ENHANCEMENT REGIME

The geometry that we consider here is a GaAs/AlAs micropillar with circular section containing a GaAs cavity with an InAs QD array at its center. We assume that the pillar diameter is small enough for resonant modes to be spectrally well separated, and we focus our attention on the coupling of QDs to the fundamental mode $HE_{11}$, which is doubly polarization degenerate. Note that the results derived hereafter can be generally applied to any microcavity geometry. For peda-
ological purposes, we first consider a hypothetical situation where in the plane perpendicular to the micropillar axis, all the QDs are located at the center of the pillar, i.e., at the spatial maximum of the mode electromagnetic field. This is not a realistic situation but in that case the calculations are analytical and contain all of the relevant physics. The mode has a quality factor $Q$ and an effective volume $V$ (see Ref. 13 for a definition of the effective volume) and resonates at energy $E_0$. We suppose in the entire paper that the QD density is sufficiently low and the quality factor is sufficiently small so that reabsorption of cavity photons by the QDs can be neglected. The Purcell factor is given by $F_p = \frac{3}{4\pi} \frac{\omega_0}{n^2}$, where $n$ is the refractive index of GaAs. It is assumed that the QDs have an in-plane dipole, as observed experimentally for their fundamental interband optical transition. Finally, we assume that the experiment is performed at low temperature under weak excitation conditions so that the emission spectrum of a single QD consists of a single narrow excitonic emission line.

The radiative emission rate for a quantum dot emitting at energy $E$ and located at the center of the pillar is then given by

$$\Gamma(E) = \Gamma_0 \left[ F_p \frac{E_0^2}{4Q^2(E-E_0)^2 + E_0^2} + \gamma \right] = \Gamma_0[F_pL(E) + \gamma],$$

(1)

where $\Gamma_0$ is the radiative emission rate of the InAs QDs in a homogenous GaAs matrix, $(\gamma \Gamma_0)$ is the emission rate in the leaky modes of the pillar, and $L(E)$ is the Lorentzian spectral distribution of the fundamental cavity mode. In general, $\gamma$ is slightly less than unity when the QD emits within the Bragg reflector stop band [ $\gamma \sim 0.8$ (Ref. 7)] due to the fact that the spectral density of leaky modes seen by a QD in a micropillar is less than the density of modes in a homogeneous matrix. This effect is, however, quite small and negligible in the case of large $F_p$ microcavities that we study in this paper, so we shall take here $\gamma = 1$ for all numerical examples. Note that for photonic crystal cavities, $\gamma$ can be significantly smaller than 1. Equation (1) gives the total QD spontaneous emission rate, taking into account the fact that the micropillar modes are polarization degenerate, the partial emission rates are $\Gamma_0 F_pL(E)$ in the cavity mode and $\gamma \Gamma_0$ in the leaky modes. The fraction of the QD spontaneous emission that is emitted in the mode, $\beta(E)$, can be written as

$$\beta(E) = \frac{\Gamma_0 F_pL(E)}{\Gamma(E)} = \frac{F_pL(E)}{F_pL(E) + \gamma}.$$

We now estimate the number of photons that are actually detected by the detector in the PL experiment. Let us call $A$ and $B$ the collection plus detection efficiencies for photons emitted in the cavity mode and in the leaky modes, respectively. Parameters $A$ and $B$ depend on the detection setup. If a given QD emits $I_{QD}(E)$ photons per second, then the detected signal coming from this particular QD is

$$I(E) = A I_{QD}(E) \frac{\Gamma_0 F_pL(E)}{\Gamma(E)} + B I_{QD}(E) \gamma \frac{\Gamma_0}{\Gamma(E)} = A I_{A}(E) + B I_{B}(E).$$

(2)

The first term represents the emission in the mode, which appears as a positive peak in the PL spectrum, while the second term represents the emission into the leaky modes.

In general when collecting photons stemming from a micropillar cavity along the pillar axis, $A$ is much larger than $B$ (this is also true for other microcavities as long as the collection setup is well adapted to collect the far-field emission stemming from the mode), so in a PL experiment the mode signal (first term) appears as an intense positive peak against a weak background (second term). Let us then focus in this part on the first term related to the mode emission. By developing $L(E)$, $I_A(E)$ can be rewritten as

$$I_A(E) = I_{QD}(E) \frac{F_p}{F_p + \gamma} \frac{E_0^2}{4\gamma^2(E-E_0)^2 + E_0^2}. \quad (3)$$

If now one assumes that all QDs are excited at the same pump rate, that the quantum emission yield is unity for all QDs, and that all QDs are well below saturation (i.e., the probability to have a biexciton in the QD is vanishingly small), then $I_{QD}(E)$ is independent of $E$ and equal to the pumping rate per QD $P_{exc}$. All these assumptions hold when exciting the QDs nonresonantly at low temperature and low enough power. We also note that if one performs a PL experiment under pulsed excitation, then the number of excitons created in each QD per excitation cycle is the same for all QDs so that again $I_{QD}(E)$ is independent of $E$. Under such conditions, the PL spectrum reflects the spectral dependence of the spontaneous emission coupling factor in the mode $\beta(E)$. One then sees from Eq. (3) that the collected signal from the mode has a Lorentzian spectral shape, however, with a linewidth of $\frac{2\gamma^2}{\gamma^2 - 1}$. This means that as soon as the Purcell factor becomes of the order of $\gamma$, the measured linewidth at low power does not reflect the quality factor of the mode but an apparent $Q$ value which is smaller by a factor of $\frac{\sqrt{\gamma}}{\gamma}$. We also point out that the same analysis should be applied to determine the spectral dependence of the PL intensity collected from a single QD being tuned in and out of resonance with a cavity mode.\(^{18,19}\)

The physical explanation behind this phenomenon is actually quite intuitive. In the limit of vanishingly small Purcell factor, $\beta(E)$ is proportional to $L(E)$ so the spectral shape of the collected PL reflects the spectral density of states of the confined mode. On the opposite, in the limit of a strong Purcell factor, $\beta(E)$ becomes close to one even for QDs that are quite off resonance with the mode peak. Thus all QDs that couple reasonably well to the mode emit practically all of their photons in the cavity mode, which broadens the spectrum of the PL signal stemming from the mode.

As discussed earlier, the situation depicted here is not realistic. In the experiments that are actually performed, the QDs are spatially distributed all over the section of the mi-
cropillar so they all couple differently to the mode. In order to account for this spatial QD distribution, one can rewrite Eq. (2) as

\[
I(E, \vec{r}) = A_{IQD}(E, \vec{r}) \frac{F_p L(E) |E_{xy}(\vec{r})|^2}{F_p L(E) |E_{xy}(\vec{r})|^2 + \gamma} \\
+ B_{IQD}(E, \vec{r}) \frac{\gamma}{F_p L(E) |E_{xy}(\vec{r})|^2 + \gamma}
\]

\[
= A_{IQD}(E, \vec{r}) + B_{IQD}(E, \vec{r}),
\]

(4)

where \( \bar{E}_{xy}(\vec{r}) \) is the mode in-plane electric field at the location of the QD (normalized to its maximum value). In order to obtain the collected spectrum, one has to sum over all QDs that spatially couple to the mode

\[
I(E) = \int \int \left( A_{IQD}(E, \vec{r}) \frac{F_p L(E) |E_{xy}(\vec{r})|^2}{F_p L(E) |E_{xy}(\vec{r})|^2 + \gamma} \\
+ B_{IQD}(E, \vec{r}) \frac{\gamma}{F_p L(E) |E_{xy}(\vec{r})|^2 + \gamma} \right) d\vec{r}
\]

\[
= A_{IQD}(E) + B_{IQD}(E).
\]

(5)

In that case, the linewidth of the PL peak is spectrally broader than the cavity mode by a factor of \( \sqrt{\frac{\text{FWHM}}{\gamma}} \), where the effective Purcell factor \( F_p^{\text{eff}} \) is obtained by averaging the magnitude of the Purcell effect over all possible positions of the QDs within the mode area (it is assumed that the QD density is spatially uniform). The ratio between the effective Purcell factor and the microcavity Purcell factor is of the order of 3–4 and depends on the micropillar diameter and quality factor.\(^7\) For instance for a micropillar with \( Q \approx 2300 \) and diameter of 1 \( \mu \text{m} \) resonating around 1.3 eV, the Purcell factor is 28 and the effective Purcell factor (as defined in this paper) is 8.6. This means that under low excitation conditions, a PL linewidth corresponding to a quality factor of around 700 would be measured on such a micropillar. Let us note that for such a micropillar, the two conditions set at the beginning of the paper for spectrum smoothness and absence of reabsorption can be fulfilled simultaneously. Indeed, if we assume an inhomogeneous broadening of 30 meV for the InAs QDs ensemble and a homogeneous linewidth of about 15 meV (which is the case under nonresonant pumping\(^20,21\)), then the condition \( \Delta E_{\text{hom}} > \Delta E_{\text{inh}} \) implies that the number of QDs in the micropillar should be larger than 2000. This can be fulfilled for instance by having 5 QD arrays of density \( 5 \times 10^{10} \) cm\(^{-2} \) in the micropillar. Note that in that case, there are about 40 QDs emitting within the fundamental mode full width at half maximum (FWHM). If the natural emission lifetime of the QDs is 1 ns, then the QDs that undergo the largest Purcell effect will emit in 35 ps, which is much larger than the cavity photon lifetime of about 1 ps, so that reabsorption can be completely ruled out.

From these results two questions then arise. (i) What happens when the excitation power is raised so that the excitonic and then biexcitonic transitions can be saturated? (ii) Is the real \( Q \) measured in the many papers published so far with microcavities containing QDs? These questions are actually linked, and we shall now study the PL behavior of a micropillar containing QDs when the excitation power is raised. The behavior of QDs as a function of excitation power is actually quite complicated.\(^22\) Beyond the well-known exciton and biexciton transitions, many particle complexes form at high power. This effect is particularly important in the case of high \( F_p \) cavity; at the power needed to saturate the excitonic transition of a QD on resonance with the mode, an off-resonance QD is well beyond saturation for its \( s \)-shell transitions. In the present case, we restrict ourselves to a simple model taking into account only the excitonic and biexcitonic transitions. In other words, we discard the effect of \( p \)-shell (and higher lying shells) carriers on the \( s \)-shell excitonic and biexcitonic transitions. While this model will not reproduce exactly the PL spectra as a function of pumping power over orders of magnitude, it gives the main results, i.e., the difference between low power excitation where all QDs emit the same number of photons (pinned by the homogeneous excitation level) and high power excitation (i.e., when the \( s \)-shell QD levels are fully occupied), for which the number of photons emitted by a QD on \( s \)-shell transitions is governed by its Purcell-enhanced spontaneous emission rate. We also assume that within the excitation power range that we consider, the homogeneous linewidth of the QD transitions remains small enough (i.e., much smaller than the cavity linewidth) so that the Purcell effect is not degraded.\(^23\) This can be for instance obtained by resonantly exciting the bottom of the wetting layer.\(^22\) For the model, we assume that the biexciton binding energy is 3 meV with a Gaussian distribution with FWHM of 0.6 meV.\(^24\) The rate equations we use for a given QD are the following:

\[
\frac{dg}{dt} = \gamma_g X - P_g,
\]

\[
\frac{dX}{dt} = \gamma_x X_2 - PX - \gamma_x X + P_g,
\]

\[
\frac{dX_2}{dt} = -\gamma_x X_2 + PX,
\]

(6)

where \( g \) is the probability to be in the ground state (empty dot), \( X \) is the probability to have a single exciton, and \( X_2 \) is the probability to have a biexciton. \( \gamma_x \) and \( \gamma_x \) are the spontaneous emission rates of the exciton and biexciton, respectively (taking into account the Purcell enhancement). \( P \) is the pumping rate per QD, which is assumed to be the same for all QDs. Solving for these equations in the steady-state regime yields

\[
I_x = \frac{P}{1 + \frac{P}{\gamma_x} + \frac{P^2}{\gamma_x \gamma_x}},
\]
pumping power for two different micropillars

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energy divided by the PL peak linewidth from 2200 at low power

geneous GaAs matrix, of pump power. It is assumed here that for a QD in a homo-

microcavity mode

One can then compute the number of photons emitted in the unit by the excitonic and biexcitonic transitions, respectively.

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spectrum and the high power spectrum is thus very large.

power

1

tons for a micropillar with diameter of 1

micropillars with a diameter of 1

black circles

IA

normalized

(IA)

FIG. 1. (Color online) Normalized spectra for the “mode” photons for a micropillar with diameter of 1 μm and Q factor of 15 000 as a function of pumping power. The decrease in the measured linewidth when the pump power is increased appears clearly.

\[ I_{X_2} = \frac{p^2}{\gamma_X \left( 1 + \frac{p}{\gamma_X} + \frac{p^2}{\gamma_X \gamma_{X_2}} \right)}, \]

where \( I_X \) and \( I_{X_2} \) are the number of photons emitted per time unit by the excitonic and biexcitonic transitions, respectively. One can then compute the number of photons emitted in the microcavity mode \( I_X \) and in the leaky modes \( I_B \) as a function of pump power. It is assumed here that for a QD in a homogeneous GaAs matrix, \( \gamma_X = \Gamma_0 = \gamma_{X_2} / 2 \). Figure 1 displays \( I_X \) (emission in the mode) for a micropillar with a diameter of 1 μm and \( Q = 15 \ 000 \) \( (F_p = 189) \). The measured \( Q \) varies from 2200 at low power \( (P = 0.01 \ \Gamma_0) \) to 13 700 at high power \( (P = 1000 \ \Gamma_0) \). The difference between the low power spectrum and the high power spectrum is thus very large.

In Fig. 2, we display the “measured \( Q \)” (i.e., PL peak energy divided by the PL peak linewidth) as a function of pumping power for two different micropillars (including the one discussed in Fig. 1). It is worth noticing that the measured \( Q \) value increases and saturates at the real \( Q \) value in the limit of strong excitation. This behavior can be understood as follows. In the strong excitation limit, the number of photons that can be emitted by a biexcitonic transition is proportional to its total spontaneous emission rate. From Eq. (2) one sees that the total emission in the mode is proportional to the Purcell enhancement and thus reflects \( I(E) \).

Let us note that measuring such linewidth dependencies as a function of power is an elegant way of measuring the average magnitude of the Purcell effect in a simple continuous-wave (cw) PL experiment. This approach is complementary to the kind of experiments that have already been performed by looking at the different saturation behaviors for off-resonance and on-resonance QDs under cw excitation to probe the Purcell effect.\(^{25-27}\)

We have thus seen in this part that in a microcavity containing QDs in the Purcell-enhancement regime, the measured quality factor for the cavity mode in a PL experiment drastically depends on the excitation power. It is only at high excitation power that the actual quality factor is measured.

III. ROLE OF THE COLLECTION GEOMETRY

So far, we have assumed that the mode emission is collected preferentially. However one can wonder what happens when the leaky modes are collected preferentially. Figure 3 represents the leaky modes intensity \( I_B \) for the same micropillar studied in Sec. II in the same power range. The cavity mode appears here as a negative peak, which makes sense; as the QDs coupled to the cavity have a high \( \beta \) factor, they emit most of their photons into the cavity mode and not into the leaky modes. In other words at low excitation power, the PL spectrum reflects \( [1 - \beta(E)] \). This spectral feature which is a simple demonstration of the Purcell effect in a cw PL experiment has oddly never been reported. This requires developing a setup which collects as few cavity mode photons as possible, which is doable for a cavity mode which emits very directionally (for instance a microdisk cavity emitting only in a narrow cone around the disk plane\(^{28}\)). To pursue the

FIG. 2. (Color online) Power dependence of the measured \( Q \) for micropillars with a diameter of 1 μm and quality factors of 2300 (black circles) and 15 000 [red (dark gray) squares].

FIG. 3. (Color online) Leaky mode intensity as a function of pumping power for a pillar of diameter 1 μm and \( Q \) factor 15 000. The spectra are vertically offset for clarity.
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FIG. 4. (Color online) Collected spectrum for a micropillar with a diameter of 1 μm and a Q of 15,000 for a detection of all emitted photons (A=B=1). The spectrum for P=0.01 is the flattest one.

Various collection possibilities, which affect drastically the measured spectra, we envision in Fig. 4 a hypothetical experiment where all photons are collected in all directions (this corresponds to A=B=1). In the absence of Purcell effect, the spectra should be completely flat. This is also what is seen in the limit of low power; in that case all QDs emit the same number of photons (pinned by the pumping power), and as they are all collected and detected with the same efficiency in that configuration, the spectrum does not show any structure. As soon as some transitions start to saturate, while others do not due to the Purcell effect, the spectrum becomes structured. At high power where all transitions are saturated, the cavity mode appears as a positive peak as transitions (biexcitonic transitions in that case) on resonance with the mode can emit more photons at saturation.

In general, a realistic experiment would have a collection situation where A and B are not equal. When studying microcavities, the experiment favors a situation where A>B to collect efficiently the cavity mode photons. In that case, the spectra are very much like the one in Fig. 1, as the mode emission dominates over the leaky mode background (note that even in the case where A=B, one recovers a situation where the mode dominates the spectrum for P above 10^3 Γ_{0}). A different situation is the one where the leaky modes are collected preferentially, while the mode photons are still collected (which is a more realistic situation than Fig. 3 for which no cavity photons are collected). Figure 5 shows the power-dependent spectra for B=10A. In that case at low power the spectrum is dominated by the cavity mode “dip” due to the less favorable collection of on-resonance photons, while at high power it is dominated by the collected mode emission despite the low collection factor A.

We therefore conclude that the PL spectrum of a QD array in a microcavity in the Purcell-enhancement regime depends both on the pumping power and on the collection geometry, especially if it disfavors the collection of cavity mode photons. Studying the PL spectrum as a function of excitation power and collection setup geometry is thus a powerful way of fully characterizing the microcavity both by measuring the quality factor and by demonstrating the Purcell effect in a simple cw experiment.

FIG. 5. (Color online) Collected spectra for a micropillar with a diameter of 1 μm and a Q of 15,000 as a function of power (normalized to P) for collection factors B=10A.

IV. DISCUSSION

A. Validity and limits of the model

We shall now come back to the validity of our model over the entire power range that we simulate. The assumptions that we have made are as follows: (a) we have taken a simple model of QD state filling taking into account only the excitonic and biexcitonic transitions and (b) we have assumed that the homogeneous linewidths of the QD transitions remain small compared to the cavity mode linewidth. We also have assumed that absorption of the cavity mode photons by the QDs is negligible, and we will not further discuss this as it would be way beyond the scope of this paper to cope with the issue of an absorbing emitter. We however point out that in a microcavity where the emitter is in large enough quantity that absorption/gain phenomena are important, linewidth narrowing also occurs when the excitation power is raised due to absorption bleaching and/or stimulated emission. In that case a precise analysis of the evolution of the mode line shape as a function of excitation power has to take into account both the phenomenon described in the present paper and the absorption and gain dependent linewidth. Concerning assumption (a), the limitation of our model is the difficulty of modeling precisely the emission dynamics of the QDs including all multiparticle states over such a large power range. Our calculations are of course correct in the low power limit where no transition saturates. The other interesting case is the high power limit. In that case, as shown for instance in Ref. 22, when exciting strongly a collection of QDs (orders of magnitudes higher than the exciton saturation), the s-shell emission saturates with an unchanged spectrum compared to the low power limit. At very high power, the s-shell emission is made of the transitions of biexcitons dressed by various p-states filling configuration. It can be assumed that these various transitions all have the same decay time as the p-state dressing shifts transition energies but
is not likely to significantly affect oscillator strengths of the s-shell transitions. Coming back to an ensemble of QDs excited at very high power and coupled to a cavity mode, various QD dressed biexcitonic transitions will feed the mode, each of them shifting spectrally with the variation in p-state occupation. Averaged over all the QDs, the mode is fed by a constant number of saturated transitions that all have similar radiative recombination rates, and we are thus in the same situation as in our simple model. We thus can say that in Fig. 2, the low power part (below $\Gamma_0$) and the high power part (above $\sim 100$ $\Gamma_0$ for both cases considered here, although the limit for this validity zone of course depends on the cavity Purcell factor) are correct despite the limitations of our model. There can however be discrepancies between actual experiments and our simple model in the intermediate power zone. In particular in this intermediate range of excitation power, what can happen is that QDs for which neither the excitonic nor the biexcitonic lines are in resonance with the mode have p-state dressed biexcitonic transitions that are in resonance with the mode. This effect will certainly affect the mode intensity as more transitions will feed the mode compared to what is forecasted by our model. This will however marginally affect the mode spectral shape as these dressed biexcitonic transitions behave like regular biexcitonic transitions in terms of lifetime and saturation behavior.

Assumption (b) can be valid when exciting resonantly the bottom of the wetting layer. However in most cases when exciting higher in energy, the QD transitions broaden considerably at high excitation power so that their homogeneous linewidth can become larger than the cavity mode linewidth. This then degrades the Purcell enhancement so the true cavity mode linewidth is measured in PL as in a low Purcell-factor cavity. When this type of excitation power-induced broadening occurs, the shape of the curves in Fig. 2 will still be the same; only the transition to the high power regime where the real cavity $Q$ is measured will occur for smaller excitation powers due to the degradation of the Purcell enhancement that occurs as the power is raised.

**V. CONCLUSION**

As a conclusion, we have shown that the PL spectra measured on an ensemble of QDs embedded in a large Purcell-factor microcavity depend strongly on the excitation conditions and on the collection setup. It is thus very important to have a good understanding of the experimental conditions when measuring a quality factor in PL. The correct quality factor is in particular measured in the limit of strong excitation power when all transitions are saturated. By analyzing the measured quality factor variations when changing the excitation power, it is possible to demonstrate the Purcell effect in a simple cw PL experiment. Moreover, proof of the Purcell effect can also be obtained by observing a dip in the PL spectrum when collecting mostly photons emitted in the leaky modes. Finally we point out that a reliable protocol to measure the $Q$ factor by PL consists of decreasing the Purcell enhancement by increasing the homogeneous broadening of the QD transitions. This can be obtained by raising the sample temperature and/or by exciting at high enough power.

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E. M. Purcell, Phys. Rev. 69, 681 (1946).


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